OSRAM PLT3 520D **Datasheet**





Metal Can TO38

PLT3 520D

Green Laser Diode in TO38 ICut Package

Optical output power (continuous wave): 110 mW (Tcase=25°C)











Applications

- Appliances & Tools
- Entertainment
- Functional Illumination

- Outdoor & Industrial Lighting
- Projection
- Visualization

Features

- Efficient radiation source for cw and pulsed operation
- Single mode semiconductor laser
- High modulation bandwidth
- Miniaturized TO38 ICut package
- Laser diode isolated against package
- Typical emission wavelength: 520 nm



Ordering Information

Туре Peak output power Ordering Code

> typ. $\mathsf{P}_{\mathrm{opt}}$

110 mW PLT3 520D Q65112A6822



Maximum Ratings

 $T_{\rm C}$ = 25 °C

Parameter	Symbol		Values
Operating temperature	T _{op}	min.	-10 °C
	O P	max.	60 °C
Storage temperature	T _{stg}	min.	-40 °C
	Sig	max.	85 °C
Peak output power	P_{opt}	max.	120 mW
Reverse voltage 1)	V_R	max.	2 V
Soldering temperature	T_{s}	max.	260 °C
t _{max} = 10 s	Ç		

Operation outside these conditions may damage the device. Operation at maximum ratings may influence lifetime.



Characteristics

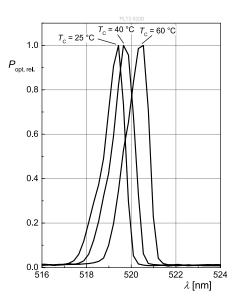
 P_{opt} = 110 mW; T_{case} = 25 °C

Parameter	Symbol		Values
Operating current ²⁾	l _{op}	typ.	225 mA
		max.	260 mA
Operating voltage 3)	V_{op}	typ.	6.1 V
		max.	7.0 V
Peak wavelength 4)5)	λ_{peak}	min.	515 nm
	P-3	typ.	520 nm
		max.	530 nm
Spectral bandwidth (FWHM)	Δλ	typ.	1 nm
Beam divergence (FWHM) parallel to pn-junction	Θμ	min.	6.0 °
	"	typ.	7.5 °
		max.	9.0 °
Beam divergence (FWHM) perpendicular to pn-junction	Θμ	min.	18.0 °
		typ.	22.5 °
		max.	25.0 °
Threshold current	I _{th}	typ.	55 mA
	u.	max.	80 mA
TE polarization	P _{TE}	typ.	100:1
Modulation frequency	f	min.	100 MHz



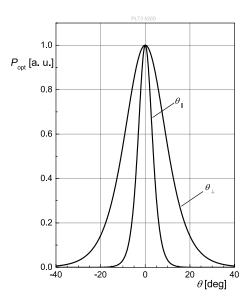
Relative Spectral Emission 6), 7)

 $P_{opt} = f(\lambda)$



Beam Divergence 7)

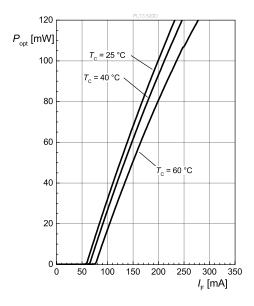
 $P_{opt} = f(\Theta)$





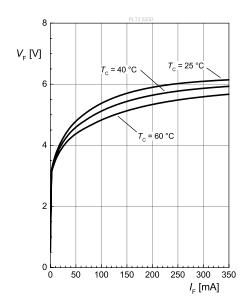
Optical Output Power 6), 7)

$$P_{opt} = f(I_F)$$



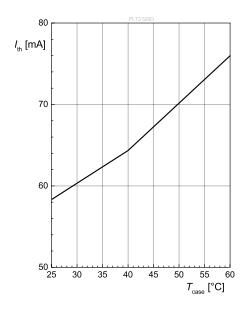
Forward Voltage 6), 7)

$$V_F = f(I_F)$$



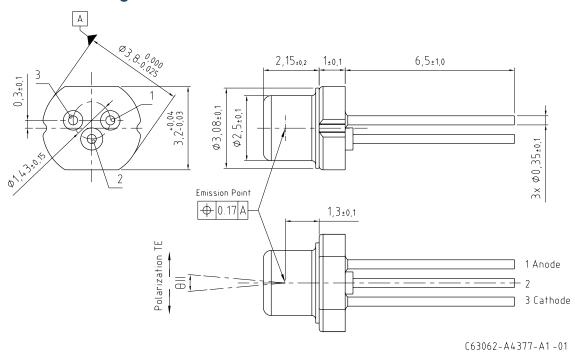
Threshold Current 6)

$$I_{th} = f(T_C)$$





Dimensional Drawing 8)



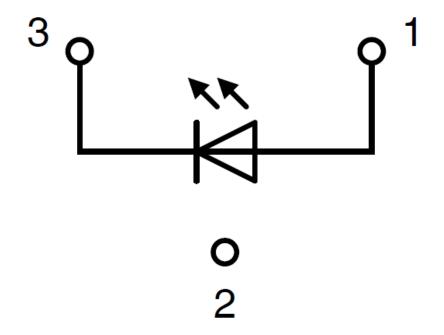
Further Information:

Approximate Weight: 141.0 mg

ESD advice: ATTENTION - Observe Precautions For Handling - Electrostatic Sensitive

Device - HBM Class 0

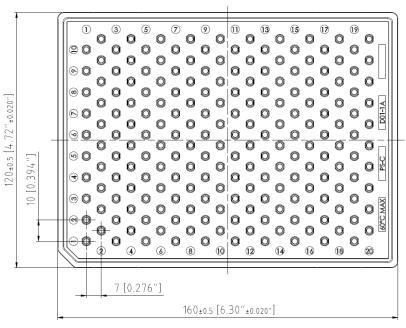
Electrical Internal Circuit



Pin	Description
PIN 1	LD Anode
PIN 2	Case
PIN 3	LD Cathode

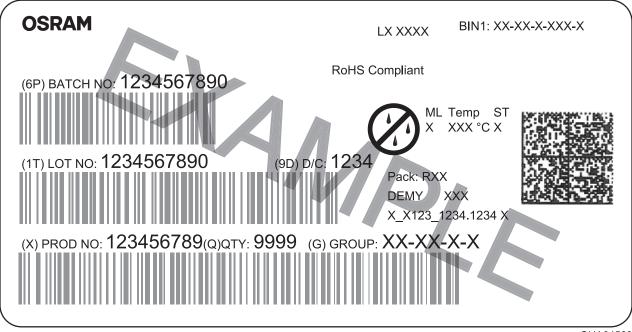


Tray 8) 200 pieces per tray



C63062-A4336-B1

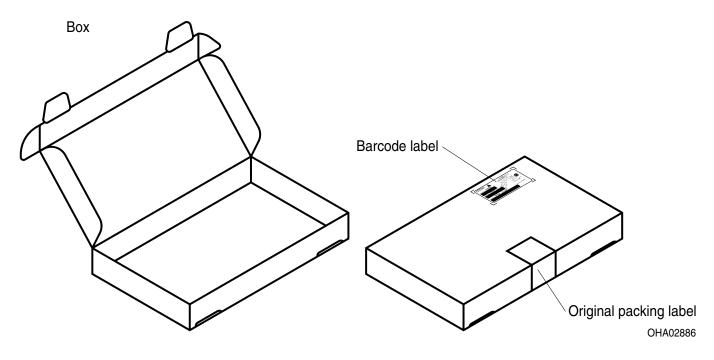
Barcode-Product-Label (BPL)



OHA04563



Schematic Transportation Box 8)



Dimensions of Transportation Box

Width	Length	Height
215 ± 5 mm	265 ± 5 mm	95 ± 5 mm



Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

Important notes of operation for laser diode

a) Electrical operation

OSRAMs laser diodes are designed for maximum performance and reliability. Operating the laser diode above the maximum rating even for very short periods of time can damage the laser diode or reduce its lifetime. The laser diode must be operated with a suitable power supply with minimized electrical noise. The laser diode is very sensitive to electrostatic discharge (ESD). Proper precautions must be taken.

b) Mounting instructions

In order to maintain the lifetime of the laser diode proper heat management is essential. Due to the design of the laser diode heat is dissipated only through the base plate of the diode's body. A proper heat conducting interconnection between the diodes base plate and the heat sink must be maintained.

For further application related information please visit https://ams-osram.com/support/application-notes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any reverse bias shall be avoided.
- 2) Operating/Forward current: IF is measured with an internal reproducibility of ±0.5 mA (acc. to GUM with a coverage factor of k = 3).
- 3) Operating/Forward voltage: VF is measured with an internal reproducibility of ±0.05 V (acc. to GUM with a coverage factor of k = 3).
- 4) Wavelength: The wavelengths are measured with a tolerance of ±0.5 nm.
- 5) Wavelength: λpeak is measured with an internal reproducibility of ±0.3 nm (acc. to GUM with a coverage factor of k = 3).
- 6) Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 7) **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



Revision	History
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Version	Date	Change
1.0	2019-01-14	Initial Version
1.0	2019-01-16	Additional Information
1.0	2019-02-01	Initial Version
1.1	2021-02-19	Applications Maximum Ratings
1.2	2022-04-01	Description Features Ordering Information Maximum Ratings Characteristics Electro - Optical Characteristics (Diagrams) Electrical Internal Circuit Tray Barcode-Product-Label (BPL) Schematic Transportation Box New Layout
1.3	2024-10-07	Characteristics Derating (Diagrams)



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Tobelbader Strasse 30, 8141 Premstaetten, Austria Phone +43 3136 500-0 ams-osram.com © All rights reserved



